

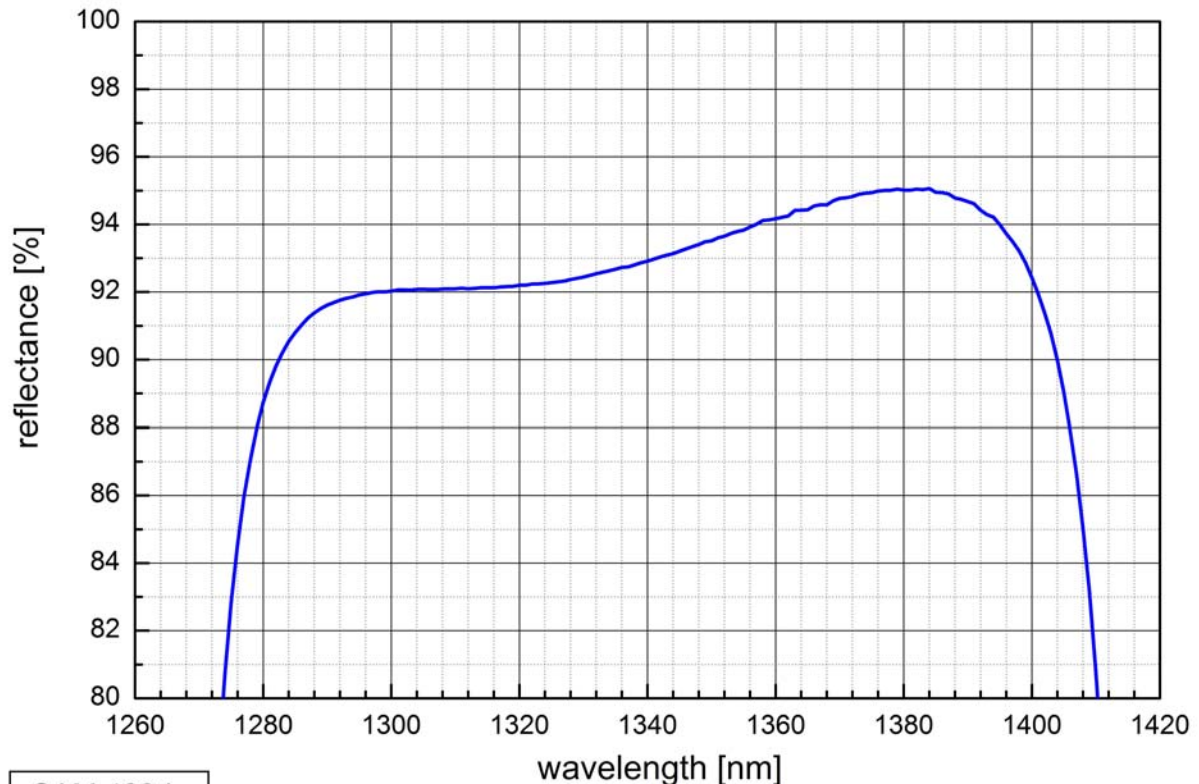
SAM™ data sheet SAM-1340-7-x-1ps, $\lambda = 1340$ nm

Laser wavelength	$\lambda = 1340$ nm
High reflection band (R > 92%)	$\lambda = 1300 .. 1400$ nm
Absorbance	$A_0 = 7$ %
Modulation depth	$\Delta R = 4$ %
Non-saturable loss	$A_{ns} = 3$ %
Saturation fluence	$\Phi_{sat} = 45$ $\mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 1$ ps
Damage threshold	600 MW/cm ² peak power density
Chip area	4mm x 4mm; other dimensions on request
Chip thickness	400 μm
Protection	the SAM is protected with a dielectric front layer

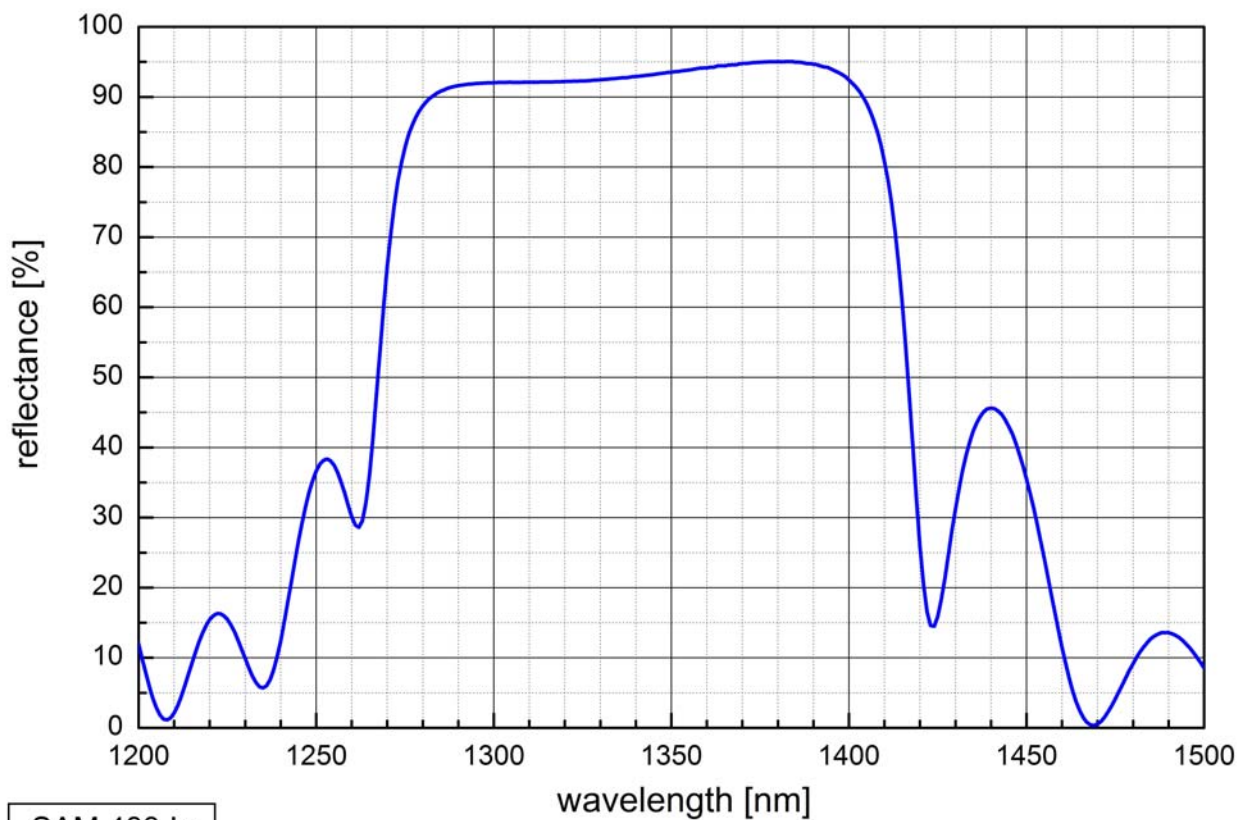
Mounting of SAM-1340-7-x-1ps denotes the type of mounting as follows:

x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 25.0 w	soldered on a water cooled Cu-cylinder with 25.4 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance



SAM 483 Ia



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